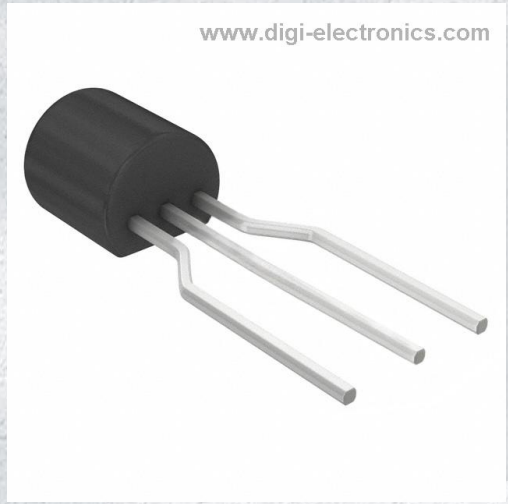
PN2222_J61Z Datasheet



DiGi Electronics Part Number	PN2222_J61Z-DG
Manufacturer	onsemi
Manufacturer Product Number	PN2222_J61Z
Description	TRANS NPN 30V 0.6A TO92-3
Detailed Description	Bipolar (BJT) Transistor NPN 30 V 600 mA 300MHz 625 mW Through Hole TO-92-3

https://www.DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PN2222_J61Z	onsemi
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	600 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
30 V	1V @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
10nA (ICBO)	100 @ 150mA, 10V
Power - Max:	Frequency - Transition:
625 mW	300MHz
Operating Temperature:	Mounting Type:
150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-226-3, TO-92-3 (TO-226AA) Formed Leads	TO-92-3
Base Product Number:	
PN2222	

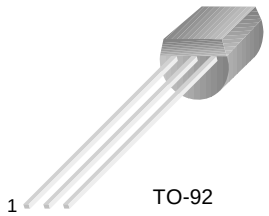
Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.21.0075

FAIRCHILD
SEMICONDUCTOR®

PN2222

General Purpose Transistor



1 TO-92

1. Emitter 2. Base 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	30	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current	600	mA
P_C	Collector Power Dissipation	625	mW
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 ~ 150	°C

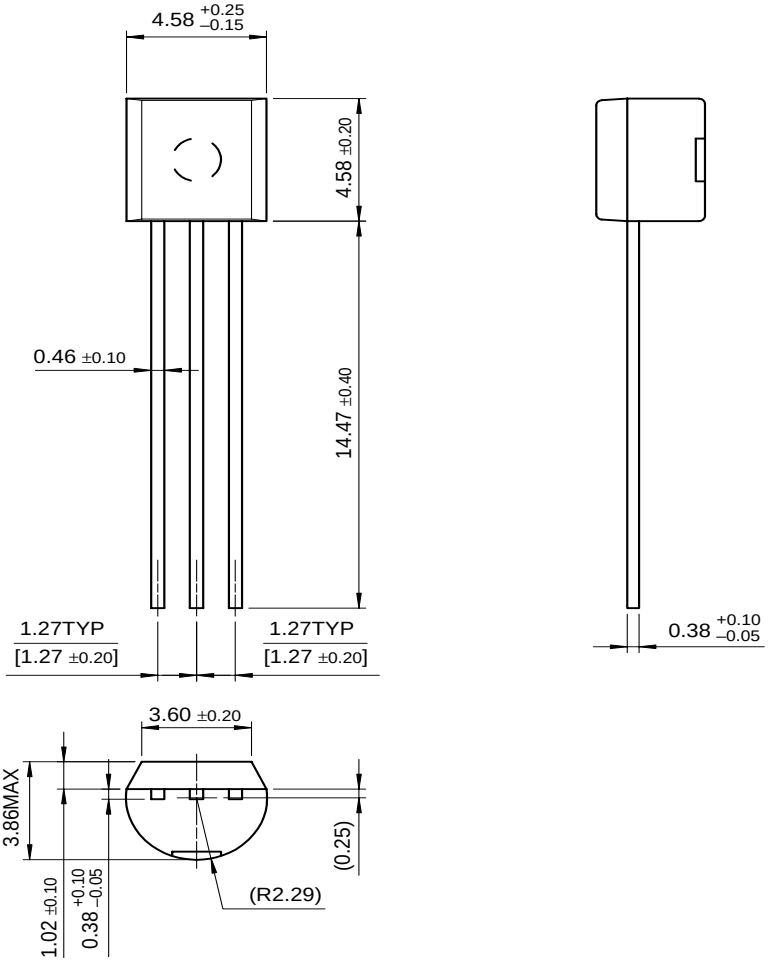
Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C=10μA, I_E=0	60		V
BV_{CEO}	Collector Emitter Breakdown Voltage	I_C=10mA, I_B=0	30		V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E=10μA, I_C=0	5		V
I_{CBO}	Collector Cut-off Current	V_{CB}=50V, I_E=0		0.01	μA
I_{EBO}	Emitter Cut-off Current	V_{EB}=3V, I_C=0		10	nA
h_{FE}	DC Current Gain	V_{CE}=10V, I_C=0.1mA V_{CE}=10V, *I_C=150mA	35 100	 300	
V_{CE} (sat)	* Collector-Emitter Saturation Voltage	I_C=500mA, I_B=50mA		1	V
V_{BE} (sat)	* Base-Emitter Saturation Voltage	I_C=500mA, I_B=50mA		2	V
f_T	Current Gain Bandwidth Product	V_{CE}=20V, I_C=20mA, f=100MHz	300		MHz
C_{ob}	Output Capacitance	V_{CB}=10V, I_E=0, f=1MHz		8	pF

* Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%

Package Dimensions

TO-92



Dimensions in Millimeters

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CoolFET™	FRFET™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	GlobalOptoisolator™	MicroPak™	QFET®	SuperSOT™-8
DOME™	GTO™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	HiSeC™	MSX™	QT Optoelectronics™	TinyLogic®
E^2CMOS™	I^2C™	MSXPro™	Quiet Series™	TINYOPTO™
EnSigna™	*i-Lo*™	OCX™	RapidConfigure™	TruTranslation™
FACT™	ImpliedDisconnect™	OCXPro™	RapidConnect™	UHC™
FACT Quiet Series™		OPTOLOGIC®	µSerDes™	UltraFET®
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Programmable Active Droop™		POP™	SPM™	

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Definition of Terms

Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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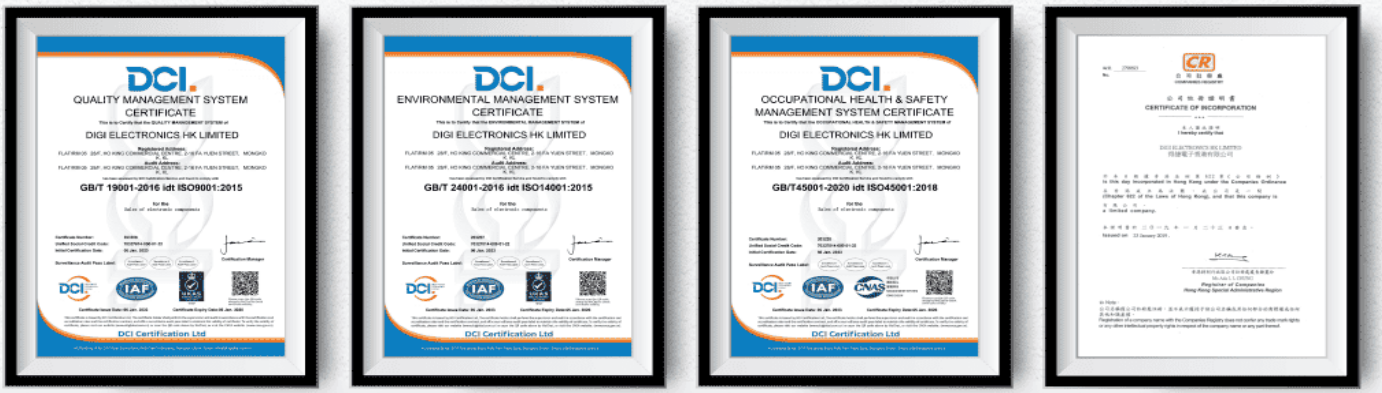

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